

2SA1309A0A Datasheet



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DiGi Electronics Part Number	2SA1309A0A-DG
Manufacturer	Panasonic Electronic Components
Manufacturer Product Number	2SA1309A0A
Description	TRANS PNP 50V 0.1A NS-B1
Detailed Description	Bipolar (BJT) Transistor PNP 50 V 100 mA 80MHz 300 mW Through Hole NS-B1



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Purchase and inquiry

Manufacturer Product Number:

2SA1309A0A

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

50 V

Current - Collector Cutoff (Max):

1 μ A

Power - Max:

300 mW

Operating Temperature:

150°C (TJ)

Package / Case:

3-SIP

Base Product Number:

2SA1309

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

100 mA

Vce Saturation (Max) @ Ib, Ic:

300mV @ 5mA, 50mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

160 @ 2mA, 10V

Frequency - Transition:

80MHz

Mounting Type:

Through Hole

Supplier Device Package:

NS-B1

Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.21.0095

ECCN:

EAR99

2SA1309A

Silicon PNP epitaxial planar type

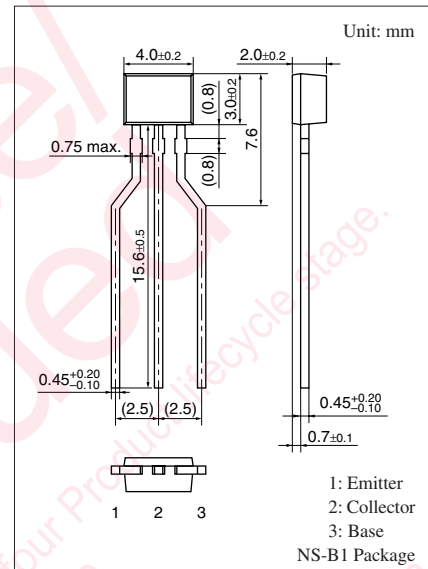
For low-frequency amplification
Complementary to 2SC3311A

■ Features

- High forward current transfer ratio h_{FE}
- Allowing supply with the radial tapping
- Optimum for high-density mounting

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	-60	V
Collector-emitter voltage (Base open)	V_{CEO}	-50	V
Emitter-base voltage (Collector open)	V_{EBO}	-7	V
Collector current	I_C	-100	mA
Peak collector current	I_{CP}	-200	mA
Collector power dissipation	P_C	300	mW
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$



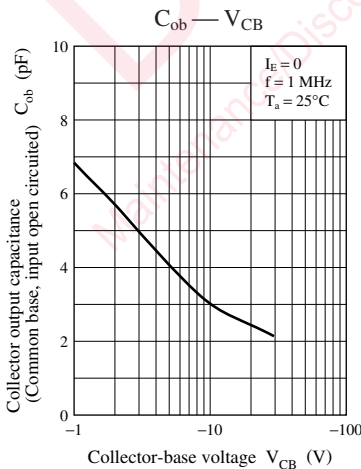
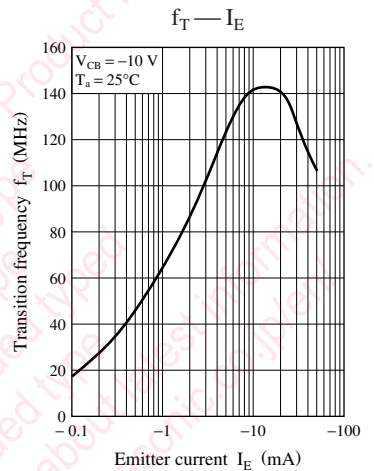
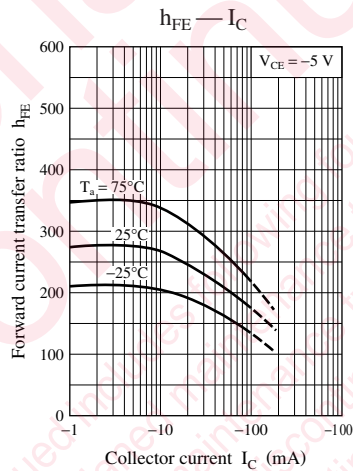
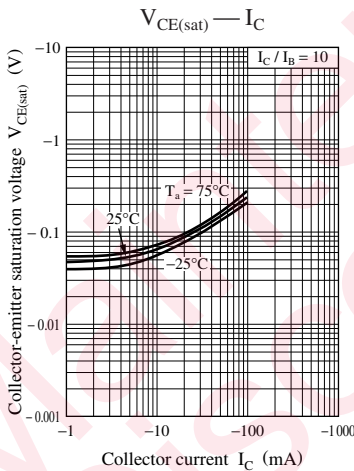
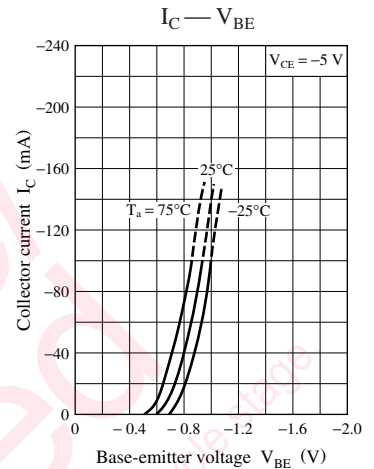
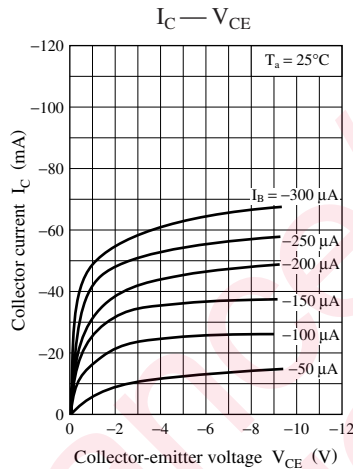
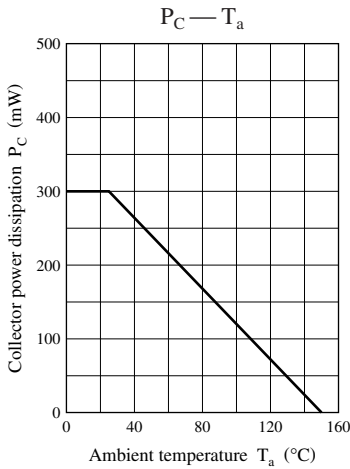
■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = -10 \mu\text{A}, I_E = 0$	-60			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = -2 \text{ mA}, I_B = 0$	-50			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = -10 \mu\text{A}, I_C = 0$	-7			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = -10 \text{ V}, I_E = 0$			-100	nA
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = -10 \text{ V}, I_B = 0$			-1	μA
Forward current transfer ratio *	h_{FE}	$V_{CE} = -10 \text{ V}, I_C = -2 \text{ mA}$	160		460	—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -50 \text{ mA}, I_B = -5 \text{ mA}$			-0.3	V
Transition frequency	f_T	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80		MHz
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		3.5		pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

Rank	Q	R	S	No rank
h_{FE}	160 to 260	210 to 340	290 to 460	160 to 460



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